## Darlington 2SD2389



Silicon NPN Triple Diffused Planar Transistor (Complement to type 2SB1559)

Application: Audio, Series Regulator and General Purpose

(Ta=25°C)

■Absolute maximum ratings (Ta=25°C)

Symbol	Ratings	Unit		
Vсво	160	V		
VCEO	150	V		
VEBO	5	V		
Ic	8	А		
lв	1	А		
Pc	80(Tc=25°C)	W		
Tj	150	°C		
Tstg	-55 to +150	°C		

## **■**Electrical Characteristics

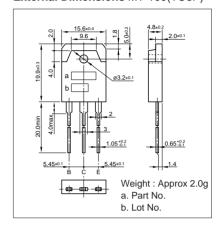
Symbol	Conditions	Ratings	Unit
Ісво	Vcb=160V	100max	μΑ
<b>І</b> ЕВО	VEB=5V	100max	μΑ
V(BR)CEO	Ic=30mA	150min	V
hfe	Vce=4V, Ic=6A	5000min*	
Vce(sat)	Ic=6A, IB=6mA	2.5max	V
VBE(sat)	Ic=6A, IB=6mA	3.0max	V
fт	Vce=12V, Ie=-1A	80typ	MHz
Сов	VcB=10V, f=1MHz	85typ	pF

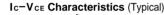
\*hFE Rank \(\overline{O}(5000 to 12000), P(6500 to 20000), Y(15000 to 30000)

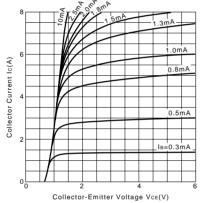
## ■Typical Switching Characteristics (Common Emitter)

Vcc (V)	R <sub>L</sub> (Ω)	Ic (A)	V <sub>BB1</sub> (V)	V <sub>BB2</sub> (V)	I <sub>B1</sub> (mA)	I <sub>B2</sub> (mA)	ton (µs)	tstg (µs)	tf (µs)
60	10	6	10	-5	6	-6	0.6typ	10.0typ	0.9typ

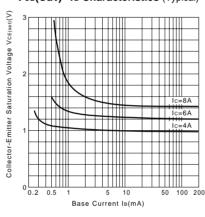
External Dimensions MT-100(TO3P)



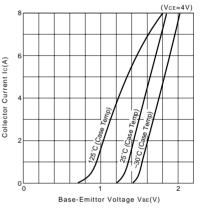




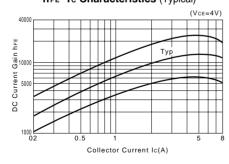
VcE(sat)-IB Characteristics (Typical)



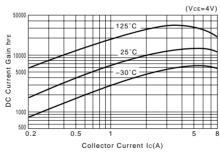
Ic-VBE Temperature Characteristics (Typical)



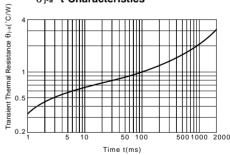
hfe-Ic Characteristics (Typical)



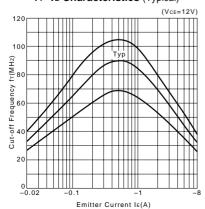
hfe-Ic Temperature Characteristics (Typical)



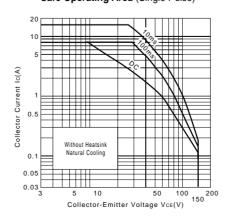
θ<sub>j-a</sub>-t Characteristics



fT-IE Characteristics (Typical)



Safe Operating Area (Single Pulse)



Pc-Ta Derating

